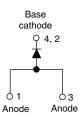


Vishay Semiconductors

Schottky Rectifier, 3.0 A





D-PAK (TO-252AA)

PRODUCT SUMMARY							
Package	D-PAK (TO-252AA)						
I _{F(AV)}	3.0 A						
V _R	20 V, 30 V, 40 V						
V _F at I _F	0.49 V						
I _{RM}	20 mA at 125 °C						
T _J max.	150 °C						
Diode variation	Single die						
E _{AS}	8 mJ						

FEATURES

- Popular D-PAK outline
- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

DESCRIPTION

The VS-MBRD320PbF, VS-MBRD330PbF, VS-MBRD340PbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS										
SYMBOL	OL CHARACTERISTICS VALUES									
I _{F(AV)}	Rectangular waveform	3.0	А							
V _{RRM}		20 to 40	V							
I _{FSM}	t _p = 5 μs sine	490	А							
V _F	3 Apk, T _J = 125 °C	0.49	V							
TJ		- 40 to 150	۵°							

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-MBRD320PbF	VS-MBRD330PbF	VS-MBRD340PbF	UNITS			
Maximum DC reverse voltage	V _R	20	30	40	V			
Maximum working peak reverse voltage	V _{RWM}	20	50	40	v			

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST COND	TEST CONDITIONS						
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T_L = 133 °C, re	3.0						
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	490	А				
	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	75					
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 16 mH	8.0	mJ					
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero i Frequency limited by T _J maximun	1.0	А					

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ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	TYP.	MAX.	UNITS				
		3 A	T.I = 25 °C	0.48	0.6	v			
Maximum forward voltage drop	V (1)	6 A	1j=25 C	0.58	0.7				
See fig. 1	V _{FM} ⁽¹⁾	3 A	T.I = 125 °C	0.41	0.49				
		6 A	1j = 125 C	0.55	0.625				
Maximum reverse leakage current	I _{RM} ⁽¹⁾	$T_J = 25 \ ^\circ C$	$V_{\rm B} = Rated V_{\rm B}$	0.02	0.2	mA			
See fig. 2		T _J = 125 °C	$v_{\rm R} = naleu v_{\rm R}$	10.7	20				
Typical junction capacitance	CT	V_{R} = 5 V_{DC} (test signal range 100 kHz to 1 MHz), 25 °C		189	-	pF			
Typical series inductance	L _S	Measured lead to lead 5 m	5.0	-	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	-	10 000	V/µs				

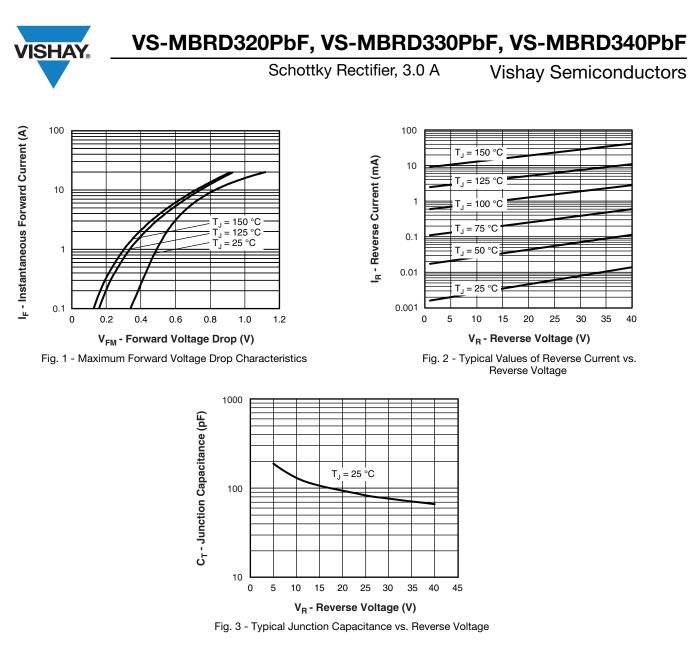
Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 $\,\%$

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction temperature range	T _J ⁽¹⁾		- 40 to 150	С°С				
Maximum storage temperature range	T _{Stg}		- 40 to 175	C				
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	6.0					
Maximum thermal resistance, junction to ambient	R _{thJA}		80	°C/W				
Approvimate weight			0.3	g				
Approximate weight			0.01	oz.				
			MBR	3RD320				
Marking device		Case style D-PAK (similar to TO-252AA)	MBRD330					
			MBRD340					

Note

(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink



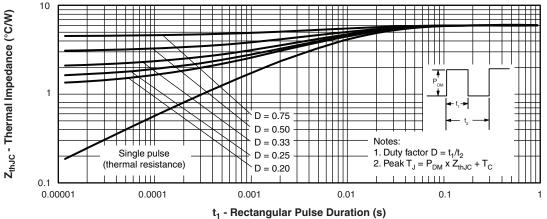


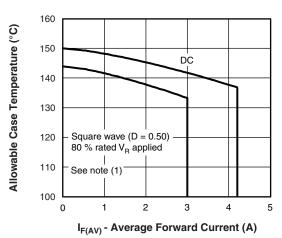
Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

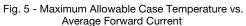
For technical questions within your region, please contact one of the following: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u>

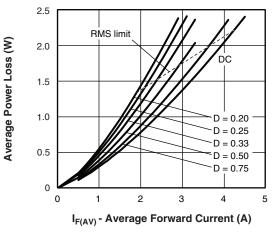


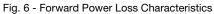
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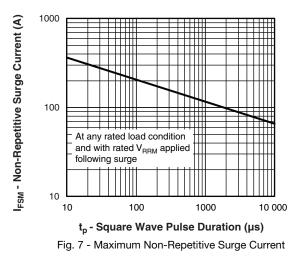
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Note

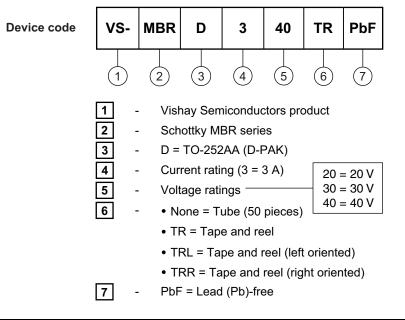
- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ x \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ x \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$



Schottky Rectifier, 3.0 A

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ORDERING INFORMATION TABLE



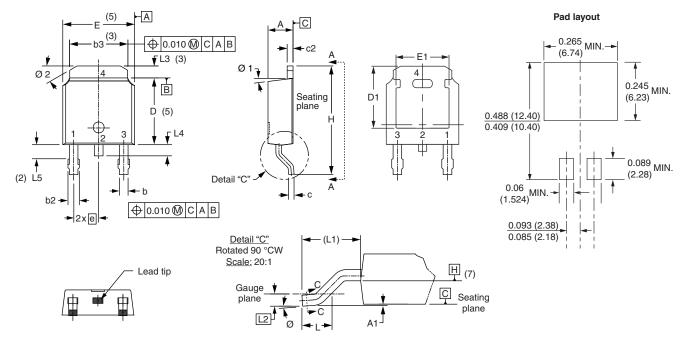
LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95016						
Part marking information	www.vishay.com/doc?95059						
Packaging information	www.vishay.com/doc?95033						





D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC	
с	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

(2) Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁶⁾ Dimension b1 and c1 applied to base metal only

⁽⁷⁾ Datum A and B to be determined at datum plane H

⁽⁸⁾ Outline conforms to JEDEC outline TO-252AA

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